

# **SBL4030PT - SBL4060PT**

### **40A SCHOTTKY BARRIER RECTIFIER**

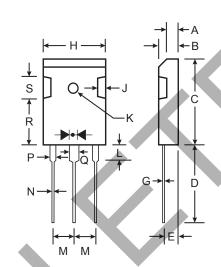
### **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- Lead Free Finish, RoHS Compliant (Note 3)

#### **Mechanical Data**

Case: TO-3P

- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Bright Tin. Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Body
- Ordering Information: See Last Page
- Marking: Type Number
- Weight: 5.6 grams (approximate)



TO-3P					
Dim	Min	Max			
Α	1.88	2.08			
В	4.68	5.36			
С	20.63	22.38			
D	18.5	21.5			
E	2.1	2.4			
G	0.51	0.76			
Н	15.38	16.25			
J	1.90	2.70			
K	2.9Ø	3.65∅			
L	3.78	4.50			
M	5.2	5.7			
N	0.89	1.53			
Р	1.82	2.46			
Q	2.92	3.23			
R	11.70	12.84			
S		6.10			
All Dimensions in mm					

## **Maximum Ratings and Electrical Characteristics**

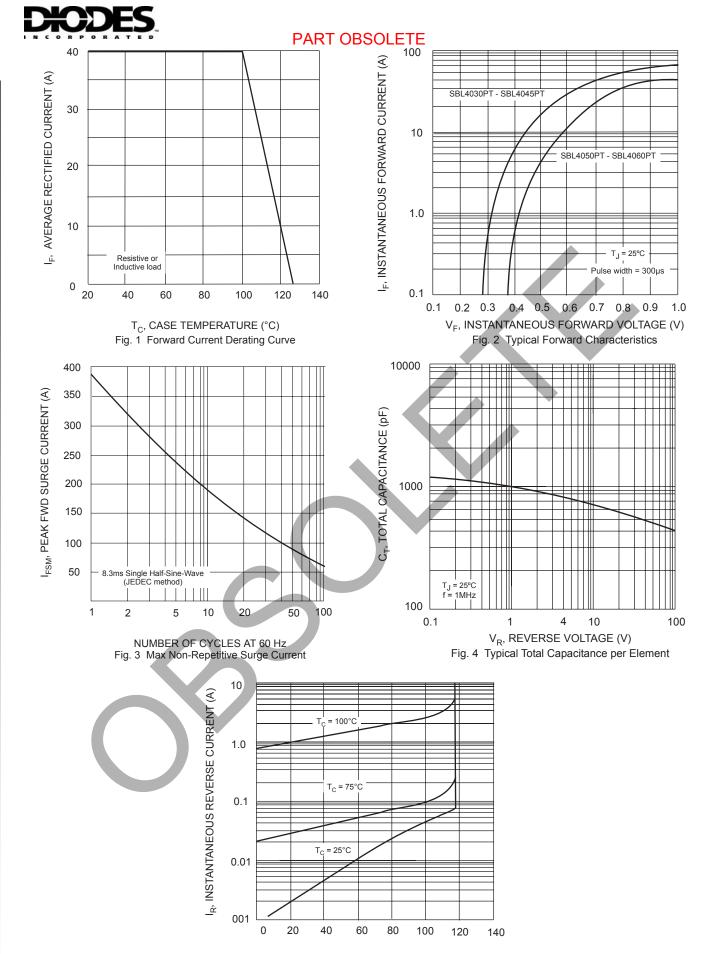
@ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SBL 4030PT	SBL 4035PT	SBL 4040PT	SBL 4045PT	SBL 4050PT	SBL 4060PT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	30	35	40	45	50	60	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	21	24.5	28	31.5	35	42	V
Average Rectified Output Current @ T <sub>C</sub> = 100°C (Note 1)		40					Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		375					А	
Forward Voltage Drop @ I <sub>F</sub> = 20A, T <sub>C</sub> = 25°C	V <sub>FM</sub>		0.	58		0.	70	V
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	I <sub>RM</sub>				.0 00			mA
Typical Total Capacitance (Note 2)	C <sub>T</sub>			80	00			pF
Typical Thermal Resistance Junction to Case (Note 1)	R <sub>θ</sub> JC			1	.4			°C/W
Operating Temperature Range		-55 to +125					°C	
Storage Temperature Range	T <sub>STG</sub>			-55 to	+150			°C

Notes:

- 1. Thermal resistance junction to case mounted on heatsink.
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.



PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5 Typical Reverse Characteristics



### **Ordering Information** (Note 4)

Device	Packaging	Shipping		
SBL4030PT	TO-3P	30/Tube		
SBL4035PT	TO-3P	30/Tube		
SBL4040PT	TO-3P	30/Tube		
SBL4045PT	TO-3P	30/Tube		
SBL4050PT	TO-3P	30/Tube		
SBL4060PT	TO-3P	30/Tube		

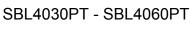
Notes: 4. For packaging details, visit our website at http://www.diodes.com/datasheets/ap02008.pdf



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